DECLARATION AND POWER OF ATTORNEY

the original, first, and sele-inventor (if or subject matter which is claimed and for w	ly one name is listed below) or	on original first and joint		•	iame; I believe	I am
subject matter which is claused and for w	high a natant is sought on the i	nuontion entitled: SVSTEM	inventor	(if plural names a	re listed below	of the
ENTITIES the specification of which I i			AND MI	ETHOD FOR ACCE		United
States Application Serial No.). <u> </u>	or	PCT	International	Application	No.
	and was amended on			(if applicable).		h.,
I hereby state that I have reviewed a amendment referred to above. I acknowled	ind understand the contents of	t the abovedentified specifi tion which is material to pate	cation, 11 entability	icluding the claims as defined in 37 CF	s, as amended R & 1.56.	by any
I hereby claim foreign priority benefits	under 35 U.S.C. § 119(a)-(d) or	§ 365(b) of any foreign app	olication(s	s) for patent or inve	entor's certifica	te or §
365(a) of any PCT international application	on(s) designating at least one co	untry other than the United	States, lis	sted below and have	also identified	below,
any foreign application(s) for patent or inv	entor's certificate, or any PCT I	nternational application(s) h	naving a f	iling date before th	at of the applic	ætion(s)
of which priority is claimed:						
Country	Application Number	Date of Filing		Priority Claimed	Under 35 U.S.C	. 119
				☐ YES	□ ио	
·				□ YES	□ NO	
I hereby claim the benefit under 35 U.S.	2 8 400(a) of any United States	emuisional application(s) lis	ted helow			<u></u>
I hereby dailin the benefit under 35 0.3.	x y 119(e) of any officed offices [Tovisional application (8) is		· ———————		
Application Number			Date of Filing			
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		1				
I hereby claim the benefit under 35 U.S. United States, listed below and, insofar a International application(s) in the manna material to patentability as defined in 37 International filing date of this application	s the subject matter of each of t or provided by the first paragra CFR § 1.56 which became avail	the claims of this application ph of 35 U.S.C. § 112, I ack	n is not d nowledge	isclosed in the prio the duty to disclose	r United States e information v	or PCT which is
	<i>'</i>					
Application Number	Dat	e of Filing	Status	: (Patented, Pendir	ng, Abandoned))
I hereby appoint the following attorne connected therewith. FINNEGAN, HER Reg. No. 20,291; Ford F. Farabow, Jr.,	NDERSON, FARABOW, GA Reg. No. 20,630; Arthur S. Jennings, IV, Reg. No. 20,645;	RRETT & DUNNER, L.I Garrett, Reg. No. 20,338,	P., Reg : Donald	z. No. 22,540, Do I R. Dunner, Reg.	ouglas B. Hen No. 19,073; E	aerson, Brian G.

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Road, Palo Alto, California 94303.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

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